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Chemical substitution in spinel structured LiZnNbO₄ and its effects on

the crystal structure and microwave performance

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Abstract:

LiZn_{1-x}M_xNbO₄ (M=Co, Ni) (x=0-0.06) systems were fabricated by a facile solid-state

reaction method. Structure and property relationships of spinel structured LiZn_{1-x}M_xNbO₄ were

investigated systematically. Appropriate amount of Co²⁺ and Ni²⁺ greatly improved the dielectric

loss of LiZnNbO₄ ceramics. While, the dielectric loss deteriorated seriously when the doping

content exceeded x=0.02. The origin of dielectric loss in LiZn_{1-x}M_xNbO₄ ceramics was

investigated systematically. Moreover, the theoretical dielectric constant and linear expansion

coefficient were calculated on the bases of the crystallographic parameters from XRD refinement.

The temperature coefficient of resonant frequency calculated by the P-V theory agreed well with

the test values. Due to the small doping content, the change in chemical bonds was negligible.

Density became the major factor determining the variation of dielectric constant in LiZnNbO₄

ceramics. At last, excellent microwave dielectric properties were obtained: Ts= 1010° C, ε_r =15.25,

 $Q_{f}=107,000GHz$, $\tau_{f}=-63.3ppm/^{\circ}C$ for $LiZn_{0.98}Co_{0.02}NbO_{4}$ and $Ts=995^{\circ}C$, $\varepsilon_{r}=14.85$,

Qf=104,000GHz, $\tau_f=-61.7ppm/^{\circ}C$ for $LiZn_{0.98}Ni_{0.02}NbO_4$.

Keywords: Lattice vibration; Raman; Dielectric loss; Band gap; Linear expansion coefficient

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